
PART NUMBER**LF157H-ROC**

Rochester Electronics**Manufactured Components**

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

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Texas Instruments.

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MICROCIRCUIT DATA SHEET

MNLF157-X REV 1A1

Original Creation Date: 06/20/95
Last Update Date: 09/12/02
Last Major Revision Date: 09/05/02

MONOLITHIC JFET INPUT OPERATIONAL AMPLIFIERS

General Description

These are the first monolithic JFET input operational amplifiers to incorporate well matched, high voltage JFETs on the same chip with standard bipolar transistors (BI-FET(TM) Technology). These amplifiers feature low input bias and offset currents/low offset voltage and offset voltage drift, coupled with offset adjust which does not degrade drift or common-mode rejection. The devices are also designed for high slew rate, wide bandwidth, extremely fast settling time, low voltage and current noise and a low 1/f noise corner.

Industry Part Number

LF157

NS Part Numbers

LF157H/883

Prime Die

LF157

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp Description

Temp (°C)

	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- Low input bias current	30 pA
- Low input offset current	3 pA
- High input impedance	10e12 Ohms
- Low input offset voltage	1 mV
- Low input offset voltage temp. drift	3 uV/ C
- Low input noise current	0.01 pA/sqrtHz
- High common-mode rejection ratio	100 dB
- Large dc voltage gain	106 dB
- Extremely fast settling time to 0.01%	1.5 uS
- Fast slew rate	50 V/uS
- Wide gain bandwidth	20 MHz
- Low input noise voltage	12 nV/sqrtHz

(Absolute Maximum Ratings)

(Note 1)

Supply Voltage	±22V
Differential Input Voltage	±40V
Input Voltage Range (Note 4)	±20V
Output Short Circuit Duration	Continuous
T _{jmax}	150 °C
Power Dissipation at Ta=25 °C (Still Air) (Note 2, 3)	560mW
(500 LF/Min Air Flow)	1200mW
Thermal Resistance	
ThetaJA (Still Air)	162 °C/W
(500LF/Min Air flow)	89 °C/W
ThetaJC	32 °C/W
Storage Temperature Range	-65 °C ≤ Ta ≤ +150 °C
Lead Temperature (Soldering, 10 seconds)	300 °C
ESD tolerance (Note 5)	1200V

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{jmax} (maximum junction temperature), ThetaJA (package junction to ambient thermal resistance), and TA (ambient temperature). The maximum allowable power dissipation at any temperature is Pdmax = (T_{jmax} - TA)/ThetaJA or the number given in the Absolute Maximum Ratings, whichever is lower.

Note 3: Maximum Power Dissipation is defined by the package characteristics. Operating the part near the Maximum Power Dissipation may cause the part to operate outside guaranteed limits.

Note 4: Unless otherwise specified the absolute maximum negative input voltage is equal to the negative power supply voltage.

Note 5: Human body model, 100pF discharged through 1.5k Ohms.

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
 DC: $V_{cc} = \pm 15V$, $V_{cm} = 0V$, $R_s = 50 \text{ Ohms}$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
Vio	Input Offset Voltage				-5	5	mV	1
					-7	7	mV	2, 3
		$V_{cc} = \pm 20V$			-5	5	mV	1
					-7	7	mV	2, 3
Iio	Input Offset Current				-0.02	0.02	nA	1
					-20	20	nA	2, 3
		$V_{cm} = 11V$			-0.02	0.02	nA	1
					-20	20	nA	2, 3
		$V_{cm} = -11V$			-0.02	0.02	nA	1
					-20	20	nA	2, 3
Ibias	Input Bias Current					0.1	nA	1
						50	nA	2, 3
		$V_{cm} = 11V$				0.1	nA	1
						50	nA	2, 3
		$V_{cm} = -11V$				0.1	nA	1
						50	nA	2, 3
PSRR	Power Supply Rejection Ratio	$V_{cc} = \pm 20V$ to $\pm 10V$			85		dB	1, 2, 3
CMRR	Common Mode Rejection Ratio	$V_{cm} = \pm 11V$			85		dB	1, 2, 3
+Vio/Adj	Input Offset Voltage Adjust				10		mV	1, 2, 3
-Vio/Adj	Input Offset Voltage Adjust					-10	mV	1, 2, 3
Icc	Power Supply Current					7	mA	1
						9	mA	2, 3
		$V_{cc} = \pm 20V$				9	mA	1
+Ios	Short Circuit Current	$V_{out} = 0V$			-35	-15	mA	1

Electrical Characteristics

DC PARAMETERS (Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: $V_{CC} = \pm 15V$, $V_{CM} = 0V$, $R_S = 50 \text{ Ohms}$

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
-I _{os}	Short Circuit Current	$V_{out} = 0V$			15	35	mA	1
+V _{op}	Output Voltage Swing	R _L 10K Ohms			12		V	4, 5, 6
		R _L 2K Ohms			10		V	4, 5, 6
-V _{op}	Output Voltage Swing	R _L 10K Ohms				-12	V	4, 5, 6
		R _L 2K Ohms				-10	V	4, 5, 6
+A _{vs}	Large Signal Voltage Gain	R _L = 2K Ohms, $V_{out} = 0$ to 10V			50		V/mV	4
					25		V/mV	5, 6
-A _{vs}	Large Signal Voltage Gain	R _L = 2K Ohms, $V_{out} = 0$ to -10V			50		V/mV	4
					25		V/mV	5, 6

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

AC: $V_{CC} = \pm 15V$, $V_{CM} = 0V$, $R_S = 50 \text{ Ohms}$

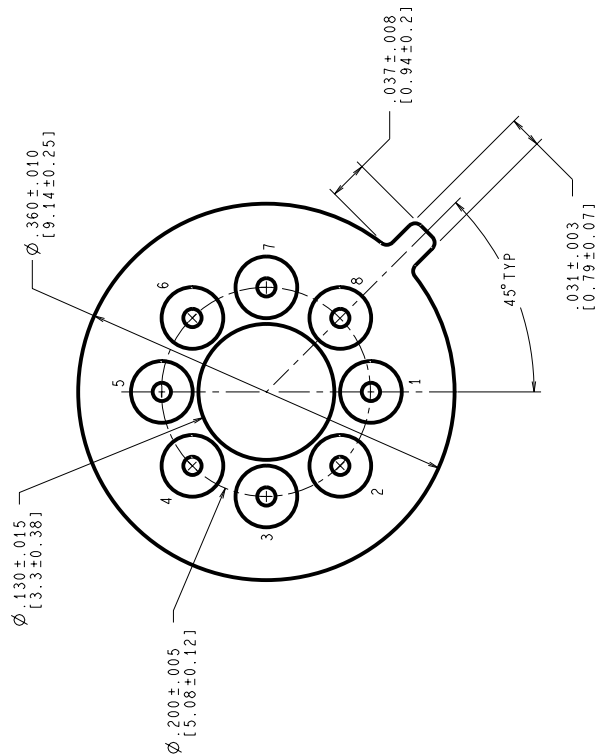
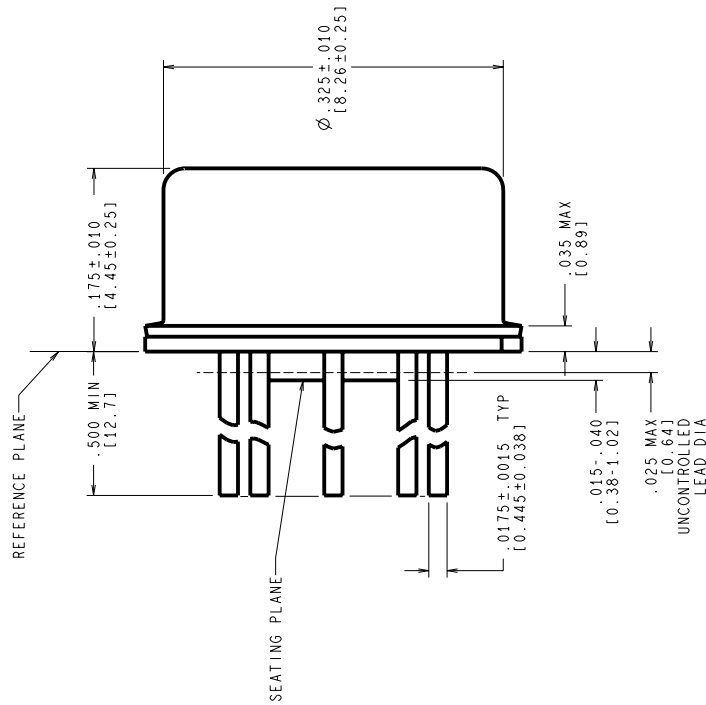
+S _r	Slew Rate	$A_v = 5$, $R_{load} = 2K \text{ Ohms}$, $C_{load} = 100\text{pfd}$, $V_{in} = -1V$ to $+1V$, $V_{out} = -5V$ to $+5V$			30		V/uS	9
-S _r	Slew Rate	$A_v = 5$, $R_{load} = 2K \text{ Ohms}$, $C_{load} = 100\text{pfd}$, $V_{in} = +1V$ to $-1V$, $V_{out} = +5V$ to $-5V$			30		V/uS	9
G _{bw}	Gain Bandwidth				15		MHz	9

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
05094HRB3	METAL CAN (H), TO-99, 8LD .200 DIA P.C. (B/I CKT)
H08CRF	METAL CAN (H), TO-99, 8LD, .200 DIA P.C. (P/P DWG)
P000295A	METAL CAN (H), 8 LEAD (PINOUT)

See attached graphics following this page.

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
F	REVISE & REDRAW PER CURRENT STANDARD: UPDATE MIL/AERO STAMP & TITLE.	11002	06/22/95
		MS/	



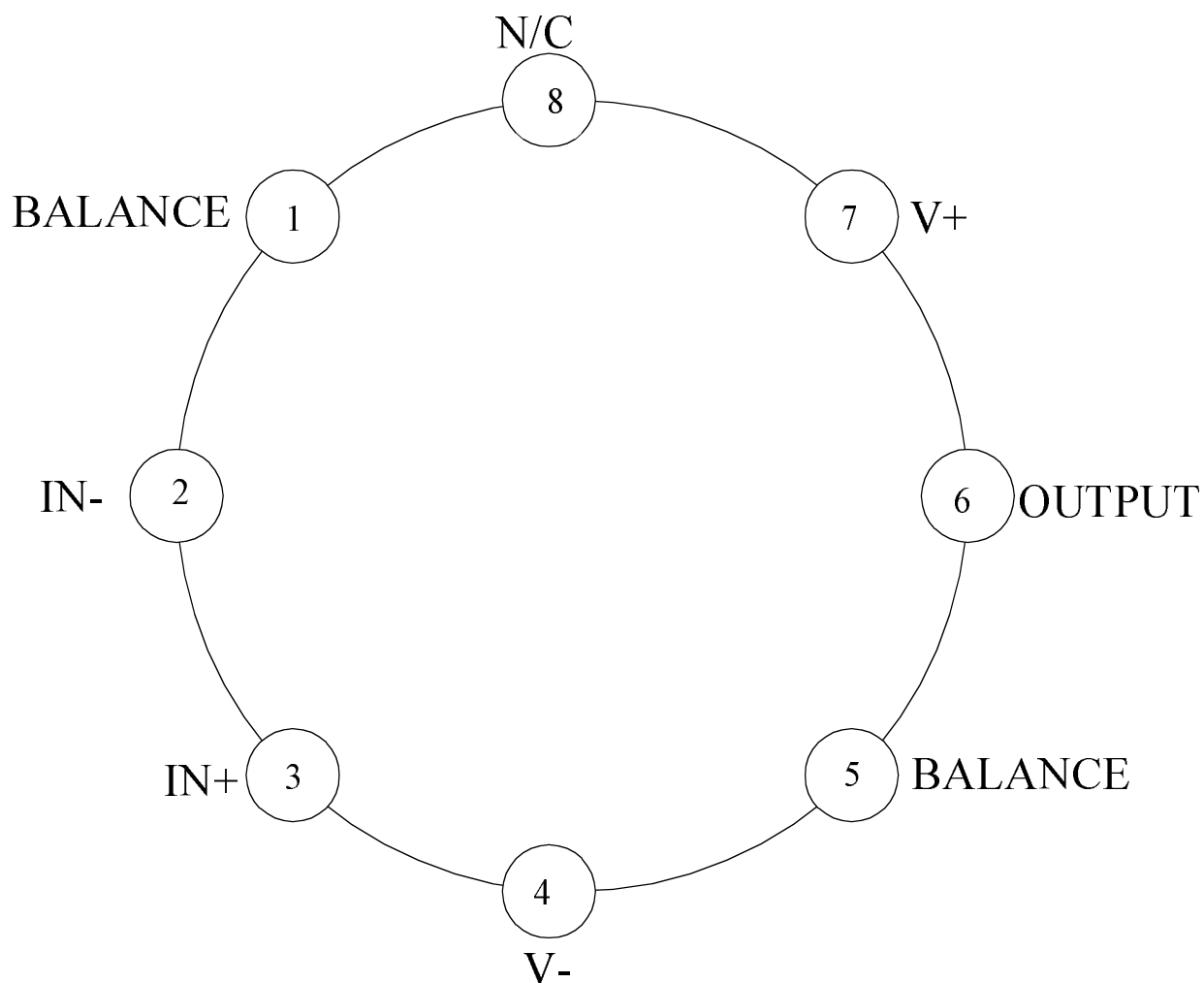
CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

MIL-I-38535
CONFIGURATION CONTROL

NOTES: UNLESS OTHERWISE SPECIFIED

- LEADS TO BE LOCATED WITHIN .007 IN/ 0.18 mm OF THEIR TRUE POSITIONS RELATIVE TO A MAXIMUM WIDTH TAB.
- STANDARD METAL CAN TYPE: SOLID BASE WITH CERAMIC STANDOFF.
- APPLIES TO MIL-AERO AND LINEAR PRODUCTS.
- REFERENCE JEDEC REGISTRATION TO-99, JEDEC PUBLICATION No.95.

APPROVALS	DATE	National Semiconductor			
DRAWN: MHTA SUC/H	06/22/95	2900 Semiconductor dr., Santa Clara, CA 95052-8090			
DTG: CH.		METAL CAN, TO-99, 8 LEAD, .200 DIA P.C.			
ENGR: CH.					
PROJECTION		SCALE	SIZE	DRAWING NUMBER	REV
		N/A	C	MKT-H08C	F
DO NOT SCALE DRAWING					
SHEET 1 of 1					



LF157AH, LF157H
8 - PIN METAL CAN
CONNECTION DIAGRAM
TOP VIEW
P000295A

Revision History

Rev	ECN #	Rel Date	Originator	Changes
1A1	M0004064	09/12/02	Rose Malone	Update MDS to fully Released datasheet: MNLF157-X, Rev. 0BL to MNLF157-X, Rev. 1A1. Changed AC Parameters Section, +SR Condition From: Av = 5, Vin = -5V to +5V TO: Av = 5, Rload = 2K Ohms, Cload = 100pfd, Vin = -1V to +1V, Vout = -5V to +5V and -SR Condition From: Av = 5, Vin = +5V to -5V TO: Av = 5, Rload = 2K Ohms, Cload = 100pfd, Vin = +1V to -1V, Vout = +5V to -5V . Condition Changed to match Test Tape.